

PUBLICATIONS

1. **Stokes, D.**, Evans, P. and Craig, C., Developing STEM Teachers through both Informal and Formal Learning Experiences, Search and Research: Teacher Education for Contemporary Context. Editors Juanjo Mena, Ana Garcia Valcarcel, Francisco Garcia-Penalvo and Marta Martin del Pozo, Publiusher Ediciones Universidad de Salamanca (July 2017).
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3. **Stokes, D.**, Evans, P., Craig, C., & Bott, S. (2016). Recruitment, Retention and Preparation of Secondary Physics and Chemistry Teachers. *American Physical Society Forum on Education Newsletter* (Fall 2016).
4. **Stokes, D.**, Forrest, R.L., Voight, C.D., Pre-testing and early Intervention in Introductory General Physics I, Publications from the 6th International Technology Education and Development Conference, Valencia, Spain (March 2012).
5. Effect of strain on the growth of InAs/GaSb superlattices: An x-ray diffraction study J. H. Li, **D. W. Stokes**, J. C Wickett, O. Caha, K. E. Bassler, and S. C. Moss *J. Appl. Phys.* **107**, 123504 (2010).
6. Short Period InAs/GaSb superlattices for mid-infrared photodetectors, H.J. Haugan, F. Szmulowicz, G.J. Brown, B. Ullrich, S.R. Munshi, S. Elhamri, J.C. Wickett and **D.W. Stokes**, *Phys. Stat. Sol.*, **4**, 1702-1706 (2007).
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10. X-ray diffraction Analysis of Interdiffusion in $Al_{1-x}In_xAs_{1-y}Sb_y$ Multilayers, R.L. Forrest, **D.W. Stokes**, J.H. Li, R. Lukic-Zrnic and T.D. Golding, *J Vac. Sci. Technol. B*, **24**, 1127-1129 (2006).
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